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REVISION 1 :

Complexions and stoichiometry of the $60.8^{\circ}/[100](011)$ symmetrical tilt grain boundary in Mg₂SiO₄ forsterite: a combined empirical potential and first-principles study

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Abstract

In this work we explore the low energy complexions of the symmetrical tilt grain boundary (GB) $60.8^{\circ}/[100](011)$ in forsterite through molecular dynamics and first principles calculations. Using conservative sampling, we find six stoichiometric complexions with energies ranging from 0.66 to 1.25 J.m⁻². We investigate the segregation of MgO vacancy pairs, and find that in most cases it is more favorable for vacancies to lie within the GBs than in the surrounding crystals, leading to new atomic structures. From these results we infer that at finite temperature when vacancies are present in the system, GBs are likely to absorb them and to be non-stoichiometric. We find many GB complexions containing a free oxygen ion, which may have profound implications for geological processes.

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1 1. Introduction

Grain boundaries (GBs) play a key role in numerous physical processes associated with mechanical, chemical diffusion or electrical conductivity behavior of polycrystalline materials (Balluffi and Sutton, 1996). Understanding their properties is therefore particularly important for a mineral like olivine which is the principal constituent of the rocks of the Earth's upper mantle. GBs are involved in several first order processes such as creep (Hirth and Kohlstedt, 1995; Maruyama and Hiraga, 2017a,b), grain boundary migration (Bollinger et al., 2019; Furstoss et al., 2021) or diffusion (Demouchy, 2010; Fei et al., 2016). At the mesoscopic scale, GBs are often viewed as interfaces with particular effective properties, like their mobility or their diffusion coefficient. Unfortunately, their structure at the atomic level is challenging to characterize. At the moment, atomically resolved observations of GB in olivine are scarce as noticed in a recent review by

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¹¹ Marquardt and Faul (Marquardt and Faul, 2018), and the few HRTEM micrographs available in literature

Fei et al. (2016); Heinemann et al. (2005); Marquardt and Faul (2018) do not allow determining the chemical

¹³ composition of GB, i.e. whether the stoichiometry is preserved or not at the GB.

In complementarity to experimental efforts, simulations at the atomic scale can provide insight towards the structure of GBs. Yet even that is challenging, due to the complex crystallography of olivine and the many possible GB configurations to explore. Nonetheless, people have used density functional theory (DFT) (Ghosh and Karki, 2014) or classical molecular dynamics (MD) (Adjaoud et al., 2012; Mantisi et al., 2017) to determine physical properties (energy, excess volume) of some select GBs in olivine. Ultimately, the comparison of numerical models with high-resolution observations will be necessary to assess the relevant GB structures, and infer their physical properties.

Description of a GB can be done at multiple scales involving different degrees of complexity and precision. 21 At the mesoscopic scale, a GB is generally described by the disorientation between the two adjacent grains, 22 and its energy is almost always described through this variable using extended Read-Shockley type models 23 (initially designed only for low angle GBs) (Gui-Jin and Vitek, 1986; Read and Shockley, 1950). However, 24 a more complete "macroscopic" description should also specify the rotation axis and the crystallographic 25 planes in contact at the GB. At smaller scales, this description can be enriched by indicating the translation 26 vector between the neighboring crystals and finally by describing the atomic arrangement of the GB (e.g. 27 bonds, stoichiometry, charge). Using these lower scale descriptions introduces supplementary degrees of 28 freedom which also impact the physical properties of GB (Han et al., 2016), and question the common 29 assumption that a given disorientation is related to a single GB structure. The multiplicity of GB structures 30 even for a given GB disorientation and contact plane has been considered by several studies essentially for 31 metals (Oh and Vitek, 1986; Rittner and Seidman, 1996) but more rarely for geological relevant materials 32 (Hirel et al., 2019). Recently the concept of GB complexion was introduced (Cantwell et al., 2014) to account 33 for the multiplicity of GB atomic structures. In spite of growing evidence that GBs in a polycrystal may 34 exist in a wide variety of complexions, numerical studies often account only for the complexion of lowest 35 energy, discarding a great number of other possible complexions. 36

In the present work we study the low-energy complexions of a particular GB in the Mg-rich end member of olivine, i.e. forsterite Mg₂SiO₄, using a combination of molecular statics and ab initio calculations. Forsterite is an orthorhombic crystal in which magnesium ions hold two distinct sites while oxygen ions (three distinct sites) are arranged in tetrahedra with a silicon ion at the center of it. In the following we use the *Pbnm* space group (where the cell parameters are ordered such as b > c > a) to describe the forsterite crystal. The

studied GB corresponds to a symmetrical tilt grain boundary (STGB) with a disorientation of 60.8° about 42 the [100] direction and (011) planes in contact at GB. This orientation has the particularity to correspond to 43 a high symmetry of the quasi hexagonal close-packed (hcp) oxygen sub-lattice. In fact in such a GB, the hcp 44 stacking of oxygen ions is almost identical to the bulk crystal, which might explain its over-representation 45 in natural olivine aggregates. Indeed, Marquardt et al. (2015) have shown from EBSD measurements on annealed forsterite polycrystals that among GB with 60° disorientation, already highly represented in the 47 misorientation distribution function, the rotation about the [100] axis with a (011) GB plane is the more 48 ubiquitous. Although first principles (Ghosh and Karki, 2014) and MD (Adjaoud et al., 2012) works have 49 examined this special STGB, both have focused on a single complexion, which raises the question of its 50 relevance and occurrence in natural systems. Most recent studies of GB in metallic systems have revealed 51 that many metastable configurations are possible and should be accounted for, arguing that materials are 52 rarely in their lowest energy state Han et al. (2016, 2017). In this work, we follow this guideline to come 53 apart from the ground-state GB structure, and explore multiple possible complexions of the GB in forsterite. Here, we first review the low-energy complexions of this STGB by determining their energies, excess volumes and by describing their atomic-scale features. Classical MD simulations allow us to probe the 56 energy landscape and identify low-energy configurations. Then, we perform ab initio calculations in order 57 to characterize more accurately the properties of these configurations. 58

Deviation from stoichiometry at GB has been noticed by several experimental and numerical studies (Baker
et al., 1990; Farkas, 2000). In fact, GBs are known to be sources and wells of vacancies and therefore it
seems interesting to explore the stoichiometry as an other degree of freedom for complexion prospecting
by deviating locally from the bulk composition at GB. In ionic compounds such as forsterite, an easy way
to deviate from stoichiometry keeping electrically neutral system is to incorporate neutral vacancy pairs.
In forsterite, the energetically most favorable Schottky defect is the MgO one (Brodholt, 1997). Thus we
investigate, in a second step, the effect of stoichiometry deviation at GB by inserting MgO vacancy pairs.

66 2. Methodology

67 2.1. Computation techniques

Atomistic calculations are performed with LAMMPS (Plimpton, 1995). Interactions between ions are modelled with a rigid-ion potential accounting for the long-range Coulomb interaction, and short-range interactions are described by a Morse function and a repulsive r^{-12} term. Potential parameters were optimized by Pedone et al. (Pedone et al., 2006), where ions have partial charges of 1.2e, 2.4e and -1.2e for

⁷² Mg, Si and O ions respectively. This allows considering neutral vacancy pairs such as MgO. Moreover this ⁷³ potential was shown to offer a very good description of a number of properties of forsterite including bulk, ⁷⁴ surfaces and defects properties (Hirel et al., 2021). Coulomb interactions are computed using the particle-⁷⁵ particle particle-mesh (pppm) method (Eastwood et al., 1980). Ion positions are optimized by means of ⁷⁶ the conjugate-gradients algorithm until the maximum force is smaller than 10^{-10} eV.Å⁻¹. The pressure is ⁷⁷ maintained at 0 GPa by rescaling the simulation cell.

In order to consolidate our results and to investigate possible changes in ionic charge state, we also perform first-principles calculations on some systems containing grain boundaries. We use the Vienna Ab initio Simulation Program (VASP) (Hafner, 2008) with the projector augmented wave (PAW) method (Kresse and Joubert, 1999) in the generalized gradient approximation (GGA) (Perdew et al., 1996). In order to treat explicitly only valence electrons, the interactions between valence, core electrons and nuclei are described by the pseudopotential developed by Perdew and Wang (1992). A cut-off of 500 eV is applied to the plane wave basis and the first Brillouin zone is sampled with Monkhorst-pack grid (Monkhorst and Pack, 1976) using a $2 \times 1 \times 1$ mesh.

First-principles calculations give access to the electron density. We perform a Bader analysis, which decomposes the charge density into atomic basins based on a change of sign in the electron density gradient
(Bader, 1990). The calculations are performed using the software "Bader Charge Analysis" developed by
the Henkelman group (Henkelman et al., 2006; Tang et al., 2009). We use it to quantify the changes in ion
charges in GBs with respect to perfect crystal environment.

91 2.2. GB construction

We focus on the $60.8^{\circ}/[100](011)$ symmetric tilt grain boundary (STGB) in forsterite, i.e. where two 92 crystals share a common [100] axis and meet along (011) planes with a disorientation of 60.8° . In forsterite, 93 two different types of (011) planes are possible, with different stoichiometries, as illustrated in Fig. 1. One 94 type of plane is terminated by a silicon ion and the oxygen ions forming the edge of tetrahedra, which we 95 will refer to as edge-planes, and the second type is terminated by Mg ions and an oxygen ion belonging to 96 the tip of a tetrahedron, referred to as tip-planes. We begin by constructing cells of forsterite terminated by 97 the same type of plane (Fig. 1). Such cells preserve the stoichiometry, but must be truncated by 1/2[001]98 (which removes one formula unit) to obtain the same type of surface. ٩q

The GB is constructed by stacking two crystals meeting across (011) planes. In order to avoid any spurious effect due to charged surfaces, we use 3-D periodic boundary conditions (PBC) and ensure that the system remains charge-neutral. Moreover, we also make sure that SiO₄ tetrahedra remain unaffected,

because breaking Si-O bonds is energetically unfavorable in this system. Since the GB studied is a STGB,
the two crystals are mirror images of each other. Two types of reference GBs are constructed, one by stacking
the "edge-plane" system with its mirror image ("edge-to-edge"), and one by stacking the "tip-plane" system
with its mirror image ("tip-to-tip").

¹⁰⁷ Due to PBC, the same GB is formed at the center of the cell and at the edges (Fig.2). This allows ¹⁰⁸ computing the reference GB energy density ($\gamma_{\rm ref}$ in J.m⁻²) and excess volume ($V_{\rm ref}^e$):

$$\gamma_{\rm ref} = \frac{E_{\rm tot} - E_{\rm bulk}}{2A},$$

$$\Omega_{\rm ref} = \frac{V_{\rm tot} - V_{\rm bulk}}{2A},$$
(1)

where E_{tot} and V_{tot} are the total energy and volume of the relaxed system containing the GBs, E_{bulk} and V_{bulk} are the total energy and volume of the equivalent defect free crystal, and A is the area of the GB.

We computed the reference GB energy for different system sizes and found that a height of 180 Å is necessary for GB energy and excess volume to be converged, which corresponds to a system containing 980 atoms. When performing DFT calculations, we use smaller systems of 420 atoms due to computational costs. Although GB energies are not converged for this system size, our convergence tests show that the atomic structure is the same as in larger systems.

116 2.3. Conservative sampling

The method described above does not guarantee an optimal atomic GB structure. An important degree of freedom is the relative translation of the two grains, quantified by a vector $\vec{\tau} = (\tau_x, \tau_y, \tau_z)$. In order to explore this degree of freedom, we impose the translation vector (τ_x, τ_y) in the GB plane, and relax ions in the direction normal to the GB to determine the optimal translation τ_z . Computing the GB energy for each translation vector, one obtains a map of the energy density γ along the GB plane. Similar to the classical generalized stacking faults approaches (Mishin and Farkas, 1998; Vitek, 1968), this method allows identifying low-energy configurations of the GB.

The use of 3D PBC requires a special attention to the simulation cell construction and the relaxation scheme involved during the relaxation process (Fig.2). Indeed if a crystal is displaced with respect to the other by keeping the same cell, then the GBs at the center and at the edges of the cell will not be equivalent anymore, thus preventing a direct calculation of the interface energy.

For this reason, when the top crystal is translated we tilt the box so that the interface at the edges of

the cell remains identical, with the energy E_{ref} . For the given relative translation $\vec{\tau}$, the energy and excess volume of the central GB are then:

$$\gamma(\vec{\tau}) = \frac{E_{\text{tot}}(\vec{\tau}) - E_{\text{bulk}}}{A} - \gamma_{\text{ref}},$$

$$\Omega(\vec{\tau}) = \frac{V_{\text{tot}}(\vec{\tau}) - V_{\text{bulk}}}{A} - \Omega_{\text{ref}}.$$
(2)

For a given imposed translation vector (τ_x, τ_y) , we relax atom positions along the direction z normal to the GB. To allow for rotational relaxation of tetrahedra, O ions are relaxed in all directions. Within 25 Å in the vicinity of the central GB, all ions are left free to relax (see Fig.2).

After the identification of the lowest energy configurations, the selected systems are fully relaxed (no ionic positions fixed) which provides the final GB complexions and allows computing their energies and excess volumes.

137 2.4. Density and excess volume

From the atomistic simulation outputs, we can compute the density profile along a direction normal to the GB plane. In practice, the mass of each atom is expanded through Gaussian distributions (with standard deviation of 2 Å) and the density profile $\rho(z)$ is computed from the contribution of all masses contained in a elementary volume (grid size of 0.2 Å). These calculations are performed with Atomsk (Hirel, 2015).

The GB excess volumes can be expressed as a function of the density profile along the direction normal to the GB plane. Indeed the density can be related to a infinitesimal change in volume dV(z):

$$dV(z) = \left(\frac{\rho_{\rm uc}}{\rho(z)} - 1\right) A dz,\tag{3}$$

where ρ_{uc} is the density of a unit cell. The GB excess volume is then computed by integrating dV around the GB in a length F, and dividing by the GB area:

$$\Omega = \int^{F} (\frac{\rho_{\rm uc}}{\rho(z)} - 1) dz \tag{4}$$

We verified that this methodology yields the same values than the ones given by Eqs. 1 and 2 in the case of stoichiometric GB structures. For non-stoichiometric GBs, Eqs. 1 and 2 are no longer valid and Ω is computed using Eq. 4.

149 3. Stoichiometric grain boundary

150 3.1. Reference grain boundaries

As explained in the previous section, the first step toward the calculation of the GB energy landscape is the construction of a reference configuration containing two equivalent GBs. After full relaxation, the edge-to-edge GB (labeled E1) has an energy $\gamma_{E1} = 0.9 \text{ J.m}^{-2}$ and an excess volume $\Omega_{E1} = 0.39 \text{ Å}$. Its atomic configuration is shown in Fig.4a. Atomic displacements after relaxation are small (about 1.15 Å) and tetrahedra do not rotate with respect to the [100] direction. Computation of the mass density profile shows that the GB is less dense than the surrounding crystals, which is consistent with the positive excess volume.

The tip-to-tip GB (labeled T1) has an energy $\gamma_{T1} = 1.22 \text{ J.m}^{-2}$ and an excess volume $\Omega_{T1} = 0.76 \text{ Å}$. Displacements are also moderate (about 1.5 Å), but are associated with significant tetrahedra rotation as shown in Fig.4d. This is probably due to strong repulsion of O ions at the tip of tetrahedra.

161 3.2. GB energy landscapes

Following the methodology presented in section 2.3 we computed the GB energy landscape for the two types of GB, which are reported in Fig.3. These landscapes are irregular and present abrupt energy variations, as it was already noticed by Adjaoud et al. (2012). Nonetheless, both surfaces exhibit a central symmetry, which is consistent with the symmetries of the (011) plane in forsterite. In addition to the reference GBs E1 and T1, each energy landscape reveals two more low energy basins, labeled E2, E3, T2 and T3. By symmetry, equivalent configurations are found, respectively E2'=E2, E3'=E3, T2'=T2 and T3'=T3 (see Fig.3).

169 3.3. Stable configurations

Each low energy configuration found from the energy landscape sampling is fully relaxed (i.e. without constraint). We obtain six distinct GB complexions with energies ranging between 0.66 and 1.25 J.m⁻². Reference GB complexions E1 and T1 were already presented above.

The complexion E2 is shown in Fig.4b. Contrary to the reference E1, it shows significant relaxation with tetrahedra sharing an O ion (orange arrow in Fig.4b), which causes an O ion to become free of any bond with a Si ion (blue arrow in Fig.4b). Although the presence of this free O ion seems unfavorable, the interface energy is $\gamma_{\rm E2} = 0.66 \text{ J.m}^{-2}$, significantly lower than the reference E1. This complexion is also more compact as evidenced by the smaller excess volume (i.e. 0.13 Å) and the density profile.

The complexion E3 is shown in Fig.4c. Like E2 it contains joined tetrahedra and free O ions, however its energy is the highest with a value $\gamma_{E3} = 1.25 \text{ J.m}^{-2}$. This complexion is the least favorable for the stoichiometric GBs. It is also associated with a large expansion ($\Omega_{E3} = 0.60 \text{ Å}$).

¹⁸¹ Concerning the tip-to-tip configurations, the complexion T2 (Fig.4e) also presents joined tetrahedra and ¹⁸² unbound O ions. Its energy $\gamma_{T2} = 1.08 \text{ J.m}^{-2}$ is lower than the reference T1. Finally, the configuration ¹⁸³ T3 also contains joined tetrahedra and free O ions. Its energy is the lowest for the tip to tip GB type, ¹⁸⁴ $\gamma_{E3} = 0.95 \text{ J.m}^{-2}$. It is also the most compact of all complexions, with an excess volume $\Omega_{T3} = 0.13 \text{ Å}$.

GB label	GB energy (J.m ⁻ 2) MD DFT		$\begin{array}{ c c } Excess volume (\AA) \\ MD & DFT \end{array}$		ΔE (eV)
E1	0.90	0.94	0.37	0.49	-2.11
E2	0.66	1.02	0.13	0.39	-1.31
E3	1.25	1.39	0.58	0.63	-2.81
T1	1.22	1.54	0.78	0.76	-1.90
T2	1.08	1.39	0.28	0.42	-2.18
Т3	0.95	1.38	0.13	0.34	-2.35
(Ghosh and Karki, 2014)		1.15		0.37	unknown
(Adjaoud et al., 2012)	1.30		0.35		unknown

Table 1: Summary of the stoichiometric GB energies and excess volumes for the different GB complexions obtained by MD and DFT. Labels refer to those in Fig.3, ΔE corresponds to the segregation energy of a MgO vacancy pair.

In summary, the most favorable complexions are E2 for the edge-to-edge type, and T3 for the tip-to-tip type. Both are characterized by tetrahedra connected by an O ion and free O ions remaining in the GB. We also note a positive correlation between GB energy and excess volume: the lower the GB energy, the lower its volume. This is consistent with previous studies on similar GBs (Adjaoud et al., 2012; Ghosh and Karki, 2014). From the density profiles we estimate the structural width of GBs to be approximately 10 Å.

190 3.4. Ab initio calculations

In order to consolidate results obtained with the interatomic potential, we performed first-principles calculations as presented in section 2.1. Starting from our previous configurations relaxed with the potential, we perform a full ionic relaxation by means of DFT calculations.

Ionic displacements are negligible, so that the GB atomic structures remain the same for all complexions. The GB energies and excess volumes obtained by DFT are reported alongside those presented previously in Tab. 1. We obtain very good agreement between the two methods, thus confirming the suitability of the potential for modeling GBs. The ordering of GB energies is identical in both methods, except for the complexions E1 and E2. This small discrepancy may be attributed to the small size of simulation volumes

involved in the DFT calculations.

Using the electron density from our DFT calculations, we performed Bader analysis to evaluate the charges 200 of ions. Fig. 5b shows the distribution of charge of O ions in a perfect bulk environment (blue curve), with a 2 01 median value about -1.61e, which we consider as the reference charge here. Charge analysis of oxygen ions 2 0 2 belonging in GBs show that the latter have little effect on this charge distribution. As an example, we show 203 the charges of O ions in the complexion E2 in Fig. 5b (orange curve). Their distribution is slightly wider 204 that in the bulk, but remains within 1% of the reference charge. Two noticeable exceptions are indicated 205 with arrows. The first one (orange S arrow) corresponds to the O ion bonding two tetrahedra, which has a 206 reduced electron charge. Visualization of its isosurface of charge density (Fig.5a) shows that it is elongated 207 in the direction of the two Si ions, which indicates mixed ionic and covalent bonding. The second exception 208 is the unbound O ion (blue F arrow in Fig. 5), which has a greater charge of about -1.65e. Its isosurface 209 is almost spherical, indicating that this ion is free of covalent bonding. Overall, we find that using an 210 interatomic potential with fixed charges is a reasonable approximation for modelling GBs in forsterite. 211

212 4. Non-stoichiometric GB: MgO vacancy pairs

We investigate the effect of stoichiometry by introducing MgO vacancy pairs in the six GBs presented above. We construct atomic systems corresponding to all possible combinations of Mg and O vacancies, which represents about 800 different systems. After relaxation, we obtain several GB complexions that can be compared with the parent GB complexion. Contrary to the stoichiometric case, the interface energy cannot be computed unambiguously, which will be discussed in section 5. For that reason, in this section we focus on the segregation energies of the vacancies, defined as the difference between the energy of a system where a vacancy pair is inside a grain ΔE_{ref}^{N-2} , and one where it lies inside the GB E_{tot}^{N-2} :

$$\Delta E = E_{\rm tot}^{N-2} - E_{\rm ref}^{N-2} \tag{5}$$

This quantity indicates if it is more energetically favorable for the vacancy to be in the bulk phase (i.e. $\Delta E > 0$) or within the GB (i.e. $\Delta E < 0$). Since in forsterite, two Mg sites and three O sites are possible in the perfect crystal, E_{ref}^{N-2} can take multiple values. We choose to take the one that minimizes ΔE , so that it vanishes in the bulk.

Fig. 6 presents the segregation energy ΔE as function of the location of the MgO vacancy pair for the complexion E1. We can see that it takes negative values everywhere within the GB, which corresponds to

the preferential segregation of vacancies at the GB. We conclude that when such vacancies are present in
the system, it is energetically favorable for them to be incorporated in the GB rather than inside a grain.
Similar results are obtained for all six complexions, and are available in the supplementary material.

229 4.1. Configurations of lowest energy

For each initial GB complexion, among all the defective configurations investigated, we select the one with the lowest energy. This leads to six final non-stoichiometric GB complexions. These complexions are associated with segregation energies in the order of -2 eV as reported in Tab. 1.

Their atomic configurations are presented in Fig. 7. In the reference complexions E1 and T1, the removal of a MgO pair causes one tetrahedron to miss an O ion and to share one with a neighboring tetrahedron.

The stoichiometric complexions E2, E3, T2 and T3 already contained connected tetrahedra and free O ions, as presented in section 3.3. One would expect the most favorable configuration to be the one where the free O ion would be removed. We find that this is true only in the complexion T3n, as shown in Fig. 4f. On the contrary, for complexions E2n, E3n and T2n, we find that the most favorable systems are the ones where the free O ions are untouched, and three tetrahedra are connected, as shown in Figs. 4b, 4c and 4e.

Although vacancies were introduced in the GBs, we find that it has a negligible impact on the formation volume, as evidenced by the density profiles shown in Fig. 7. As a result, we expect that a simple measurement of the density would not allow to discriminate between the different GB complexions. Here again, we estimate the GB structural widths to be approximately 10 Å.

244 4.2. Ab initio calculations

As for the stoichiometric complexions presented in the previous section, we perform DFT calculations on the six non-stoichiometric GBs. Starting from the configurations relaxed with the interatomic potential, we perform a full ionic relaxation with DFT. Again, we find that this relaxation does not change the atomic structure of GBs, indicating that the interatomic potential is efficient for determining GB configurations. In particular, DFT confirms the stability of tetrahedra sharing O ions, as well as the excess volumes (see supplementary materials).

We apply Bader analysis to the non-stoichiometric GBs. The results are presented for the non-stoichiometric complexion E2 in Fig. 8. As previously, the shape of isosurfaces allows to recognize mixed ionic and covalent Si-O bonds in tetrahedra, as well as free O ions. Where tetrahedra are connected, shared O ions (arrows labeled S) have a decreased charge, while others O ions belonging to those tetrahedra (arrow labeled T) have a greater charge. As before, free O ions (arrows labeled F) have a higher charge.

256 5. Discussion

257 5.1. Comparison with literature

To the best of our knowledge, we have identified for the first time six stoichiometric complexions of the 258 $60^{\circ}/[001](011)$ GB in forsterite, with formation energies ranging from 0.66 to 1.25 J.m⁻². For the same GB, 259 Adjaoud et al. (2012) reported an energy of $1.30 \text{ J}.\text{m}^{-2}$ and an excess volume of 0.35 Å using an interatomic 260 potential. First-principles calculations (Ghosh and Karki, 2014) reported an energy of 1.15 J.m^{-2} and an 261 excess volume of 0.37Å. We find that our own values are in good agreement with both numerical studies. 262 Both stoichiometric and non-stoichiometric GBs that we modeled exhibit structural widths of approximately 263 10 Å, a value commonly observed by transmission electron microscopy for GBs in olivine as reviewed by 264 Marquardt and Faul (2018). 265

Experimental determination of GB energies are more scarce. Duyster and Stöckhert (2001) measured GB energies from dihedral angles in an equilibrated coarse-grained natural peridotite. Their values span between 1.12 and 1.47 J.m⁻² which is in good agreement with our results. The values reported by Cooper and Kohlstedt (1982) are significantly lower, 0.9 ± 0.35 J.m⁻², probably due to the presence of melt at the interfaces in the olivine-basalt system considered.

The linking of tetrahedral units and the free O ions at forsterite GBs, as observed in this work, has never been 271 noticed by prior studies. The finding of Mantisi et al. (2017) that the GBs are almost structureless above 272 3 Å cannot be confirmed here. Even differing in their structures, the complexions presented here exhibit 273 a short range order which can be apprehended looking at figures 4 and 7. Some structural characteristics 274 highlighted by Ghosh and Karki (2014) are retrieved here such as the conservation of Si ions in a tetrahedral 275 environment and modification of Si-O bond lengths. A continuous treatment of this particular GB by Sun 276 et al. (2016), shows that the O and Si sub-lattices accommodate the main part of the crystal disorientation, 277 which is in good agreement with the structure of the complexions presented here. 278

The combination of first principles and MD calculations has permitted to improve the confidence on the interatomic potential of Pedone et al. (2006) to the study of GBs in forsterite. All stable complexions found with the potential have been confirmed by *ab initio* calculations with good agreement concerning the GB atomic structures, energies and excess volumes. Charge analysis have shown that the use of fixed partial charges (so-called rigid ion potential) is justified. The small deviations from the reference charge also justify the use of the interatomic potential.

285 5.2. Effect of stoichiometry

The low energy basins in the energy landscapes are separated by high energy barriers. It implies that GBs cannot change complexion conservatively (e.g. $E1 \rightarrow E2$) as it would require too much energy. Adsorption of vacancies at the GB may provide a more favourable path towards a change in GB complexion. We have shown that it is more favorable for the vacancy to be within the GB than in the bulk phase. This finding is in good agreement with the expected vacancy sinks behavior of GBs (Uberuaga et al., 2015).

As explained above, the intrinsic GB energy cannot be defined unambiguously when it is non-stoichiometric.

292 One must account for the chemical potential μ_{MgO} of the removed ions:

$$\gamma = \frac{E_{\text{tot}}^{N-2} - E_{\text{bulk}}^N + \mu_{\text{MgO}}}{A} - \gamma_{\text{ref}},\tag{6}$$

The chemical potential depends on environmental conditions. One possible choice is to define it as the 293 lattice energy of MgO periclase, which is $\mu_{MgO} = -16.57$ eV using the same interatomic potential by 294 Pedone. Nevertheless, other approximations can be done considering for instance $\mu_{MgO} = \mu_{Mg_2SiO_4} - \mu_{MgSiO_3}$ 295 (where $\mu_{Mg_2SiO_4}$ and μ_{MgSiO_3} are the lattice energies of forsterite and enstatite respectively), which gives 296 $\mu_{MgO} = -17.00$ eV; or $2\mu_{MgO} = \mu_{Mg_2SiO_4} - \mu_{SiO_2}$ (where μ_{SiO_2} is the lattice energy of quartz) which 297 gives $\mu_{MgO} = -16.44$ eV. Using these values, the GB energy of the E3n complexions (which has the lower 298 segregation energy) should range between 1.60 and $1.76 \text{ J}.\text{m}^{-2}$ which is higher than the one of the parent 299 GB (i.e. 1.25 J.m^{-2}). More generally, the energies of the non-stoichiometric complexions are higher than 300 the one of the parent GB. 301

A comparable numerical study (Chua et al., 2010) has also noticed that for different GBs in $SrTiO_3$ the most stable GBs (i.e. with lowest energies) were the stoichiometric ones, which is in contradiction with the non-stoichiometric GBs experimentally observed $SrTiO_3$ (Kim et al., 2001; McGibbon et al., 1994; Yang et al., 2013).

The GB can be viewed as a phase at equilibrium with other phase (e.g. neighboring grains) (Cantwell et al., 2014) and the minimization of the whole system energy does not necessarily lead to minimization of the GB energy itself. Our calculations show that if vacancies are present in the system, they will segregate at GBs even it increases the GB energy. The GB structure and its energy therefore depend on external factors, which emphases the lower importance to give on the GB energy to determine stable GB structures.

311 6. Implications

The atomic structure of GBs is a key input parameter, as all effective physical properties derive from it. For the one disorientation that we studied here (i.e. 60.8°), we expect each GB complexion to have different properties in terms of mobility, diffusion, segregation, and so forth. We want to stress the importance of considering all possible complexions of GBs when performing atomic-scale simulations, instead of focusing on a single particular complexion.

³¹⁷ Our work also evidences the attractiveness of GBs for vacancies (Tschopp et al., 2012; Uberuaga et al., 2015),

highlighting the exchange capacities between crystal and GBs. At finite temperature, these exchanges should
be of first importance for the structure of GBs.

A remarkable observation from our study is the presence of an anomalous non-silicate oxygen site in some GBs, which may have several implications. First, these free O ions may diffuse easier than the others (which are bound in tetrahedral environment), which could contribute to the high diffusivity of oxygen in GBs compared to bulk (Yurimoto et al., 1992). It may therefore increase the O vacancy concentration in forsterite GBs.

Second, the occurrence of such an unbound O ion is likely to have implications on water storage. The same feature is found in the structure of wadsleyite where it has been shown to strongly favor protonation (Jacobsen et al., 2005; Smyth, 1994). Our calculations suggest the possibility of a strong segregation of hydrogen at GBs with a maximum concentration of $1.74 \cdot 10^{-2}$ Å⁻² on the basis that each unbound O ion is protonated. Assuming spherical grains the contribution of such a mechanism to hydrogen storage should be of the order of 390, 40 and 4 H/10⁶Si for grain sizes of 1, 10 and 100 μ m, respectively.

Finally, some stable GBs can have relatively high free volumes and we can expect these sparsely dense boundaries to be preferential zones for incompatible elements. Further simulations are required to properly assess these hypotheses.

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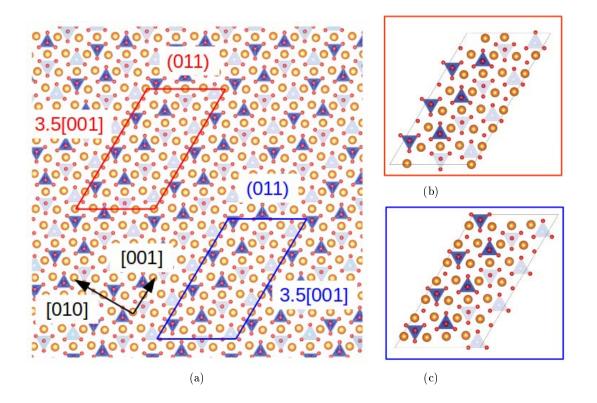


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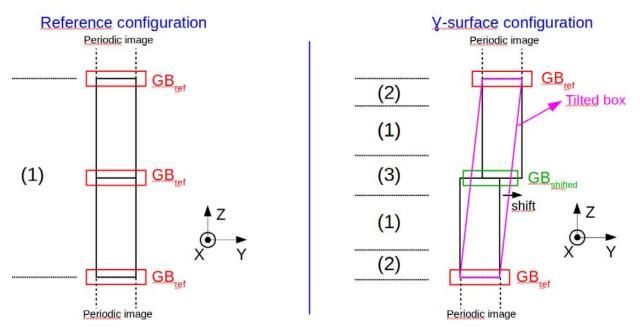


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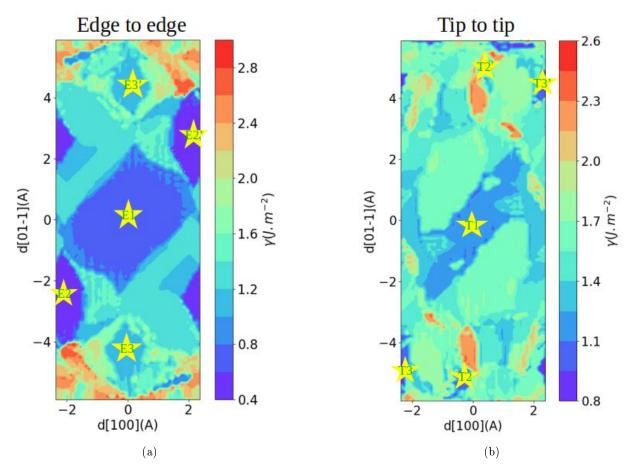


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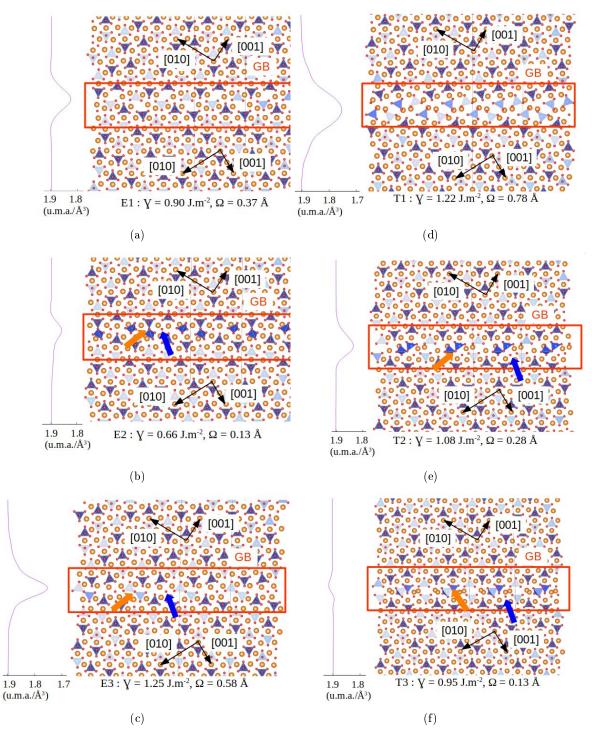


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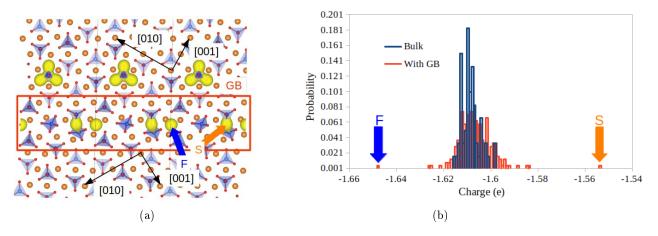


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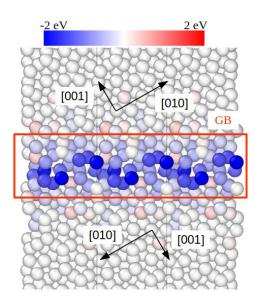


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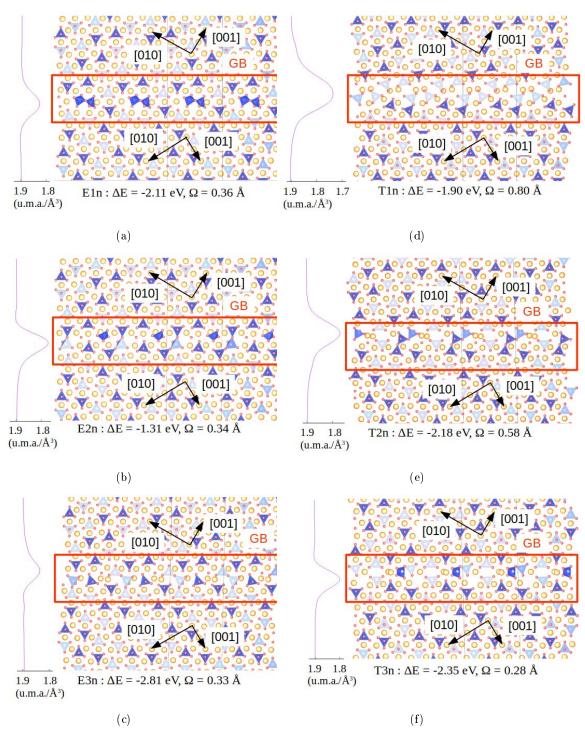


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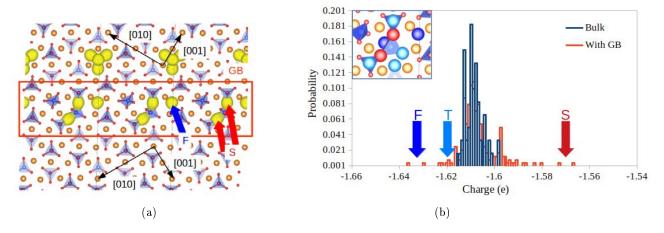


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